

5N40

Power MOSFET

5A, 400V N-CHANNEL POWER MOSFET

■ DESCRIPTION

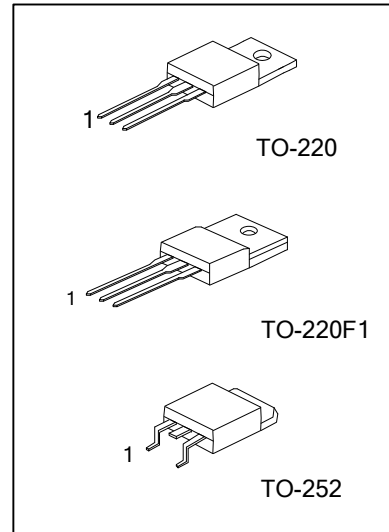
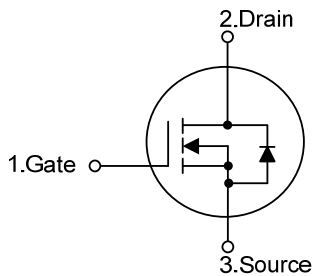
The **5N40** is an N-channel mode power MOSFET using' s advanced technology to provide customers with planar stripe and DMOS technology. This technology specializes in allowing a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode.

The **5N40** is universally applied in electronic lamp ballast based on half bridge topology and high efficient switched mode power supply.

■ FEATURES

- * $R_{DS(ON)} < 1.2\Omega @ V_{GS}=10V$
- * High switching speed
- * 100% avalanche tested

■ SYMBOL



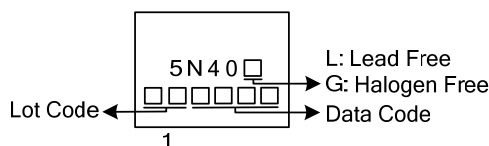
■ ORDERING INFORMATION

| Ordering Number | | Package | Pin Assignment | | | Packing |
|-----------------|--------------|----------|----------------|---|---|-----------|
| Lead Free | Halogen Free | | 1 | 2 | 3 | |
| 5N40L-TA3-T | 5N40G-TA3-T | TO-220 | G | D | S | Tube |
| 5N40L-TF1-T | 5N40G-TF1-T | TO-220F1 | G | D | S | Tube |
| 5N40L-TN3-R | 5N40G-TN3-R | TO-252 | G | D | S | Tape Reel |

Note: Pin Assignment: G: Gate D: Drain S: Source

| | |
|--|--|
| <p>5N40L-TA3-T</p> <p>(1)Packing Type</p> <p>(2)Package Type</p> <p>(3)Lead Free</p> | <p>(1) T: Tube, R: Tape Reel</p> <p>(2) TA3: TO-220, TF1: TO-220F1, TN3: TO-252</p> <p>(3) L: Lead Free, G: Halogen Free</p> |
|--|--|

■ MARKING



■ ABSOLUTE MAXIMUM RATINGS ($T_C=25^\circ\text{C}$, unless otherwise specified)

| PARAMETER | | SYMBOL | RATINGS | UNIT |
|------------------------------------|---------------------------------------|-----------|----------|------------------|
| Drain-Source Voltage | | V_{DSS} | 400 | V |
| Gate-Source Voltage | | V_{GSS} | ± 30 | V |
| Drain Current | Continuous ($T_C=25^\circ\text{C}$) | I_D | 5 | A |
| | Pulsed (Note 2) | I_{DM} | 20 | A |
| Avalanche Current (Note 2) | | I_{AR} | 5 | A |
| Avalanche Energy | Single Pulsed (Note 3) | E_{AS} | 300 | mJ |
| | Repetitive (Note 2) | E_{AR} | 7.3 | mJ |
| Peak Diode Recovery dv/dt (Note 4) | | dv/dt | 4.5 | V/ns |
| Power Dissipation | TO-220 | P_D | 69 | W |
| | TO-220F1 | | 38 | W |
| | TO-252 | | 54 | W |
| Junction Temperature | | T_J | +150 | $^\circ\text{C}$ |
| Storage Temperature | | T_{STG} | -55~+150 | $^\circ\text{C}$ |

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature

3. $L = 21.5\text{mH}$, $I_{AS} = 5\text{A}$, $V_{DD} = 50\text{V}$, $R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$

4. $I_{SD} \leq 5\text{A}$, $di/dt \leq 200\text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^\circ\text{C}$

■ THERMAL DATA

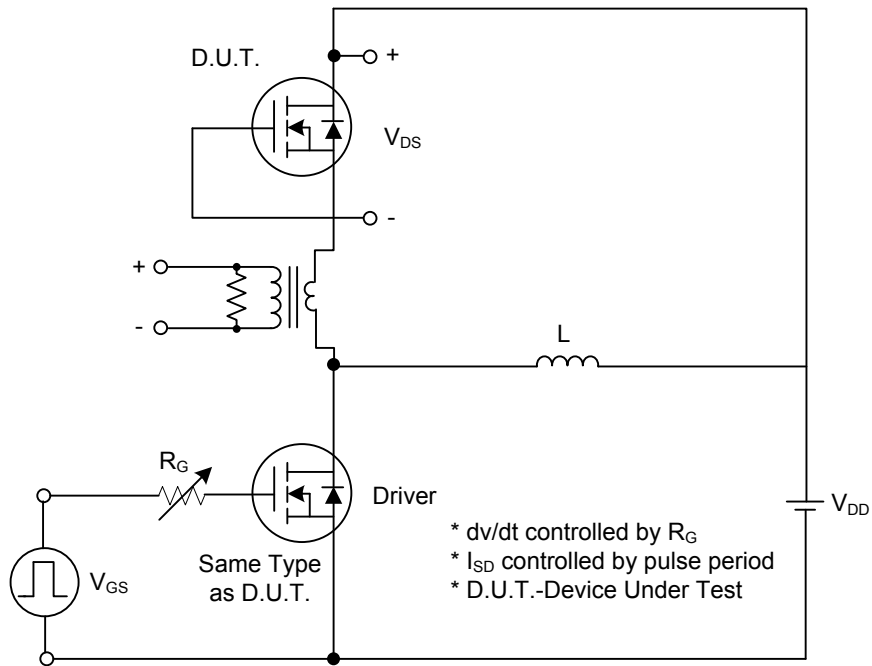
| PARAMETER | | SYMBOL | RATINGS | UNIT |
|---------------------|-----------------|---------------|---------|---------------------------|
| Junction to Ambient | TO-220/TO-220F1 | θ_{JA} | 62.5 | $^\circ\text{C}/\text{W}$ |
| | TO-252 | | 110 | |
| Junction to Case | TO-220 | θ_{JC} | 1.8 | $^\circ\text{C}/\text{W}$ |
| | TO-220F1 | | 3.25 | |
| | TO-252 | | 2.13 | |

■ ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$, unless otherwise noted)

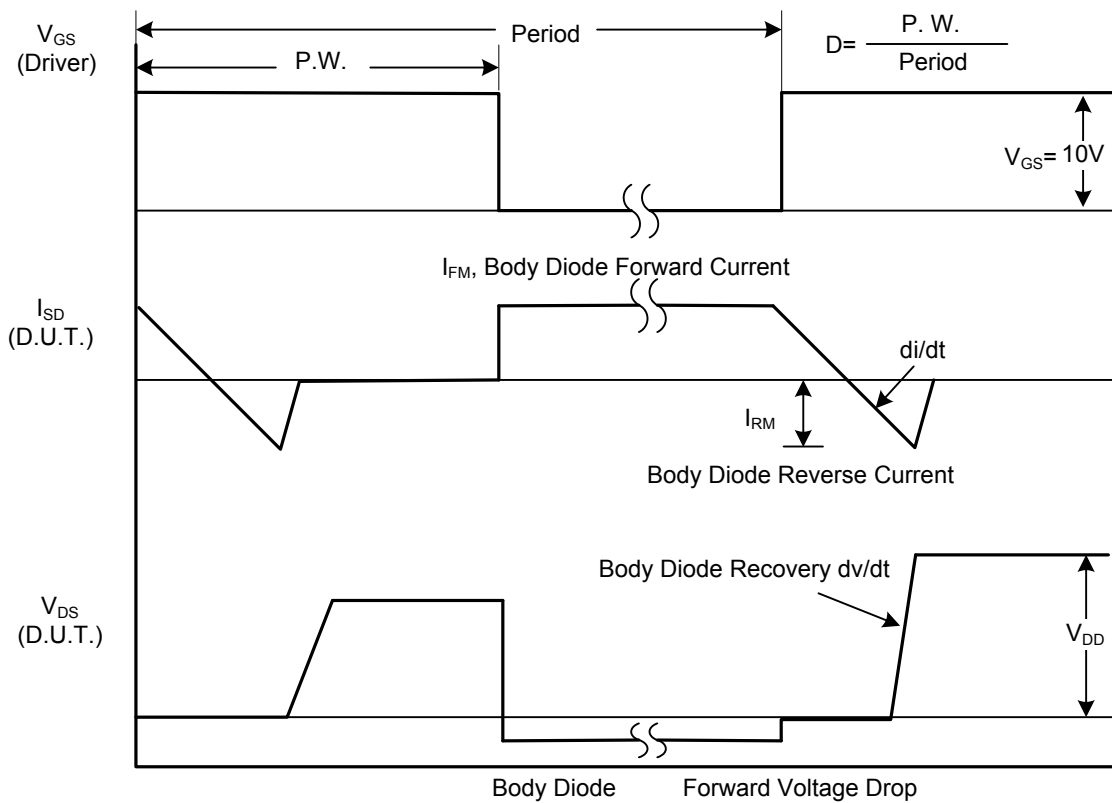
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|------------------------------|---|-----|------|------|---------------------------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $I_D=250\mu\text{A}$, $V_{GS}=0\text{V}$ | 400 | | | V |
| Breakdown Voltage Temperature Coefficient | $\Delta BV_{DSS}/\Delta T_J$ | Reference to 25°C , $I_D=250\mu\text{A}$ | | 0.4 | | $\text{V}/^\circ\text{C}$ |
| Drain-Source Leakage Current | I_{DSS} | $V_{DS}=400\text{V}$, $V_{GS}=0\text{V}$ | | | 1 | μA |
| Gate- Source Leakage Current | Forward | $V_{GS}=+30\text{V}$, $V_{DS}=0\text{V}$ | | | +100 | nA |
| | Reverse | $V_{GS}=-30\text{V}$, $V_{DS}=0\text{V}$ | | | -100 | nA |
| ON CHARACTERISTICS | | | | | | |
| Gate Threshold Voltage | $V_{GS(TH)}$ | $V_{DS}=V_{GS}$, $I_D=250\mu\text{A}$ | 2.0 | | 4.0 | V |
| Static Drain-Source On-State Resistance | $R_{DS(ON)}$ | $V_{GS}=10\text{V}$, $I_D=2.5\text{A}$ | | 0.96 | 1.2 | Ω |
| DYNAMIC PARAMETERS | | | | | | |
| Input Capacitance | C_{ISS} | $V_{GS}=0\text{V}$, $V_{DS}=25\text{V}$, $f=1.0\text{MHz}$ | | 480 | 625 | pF |
| Output Capacitance | C_{OSS} | | | 80 | 105 | pF |
| Reverse Transfer Capacitance | C_{RSS} | | | 15 | 20 | pF |
| SWITCHING PARAMETERS | | | | | | |
| Total Gate Charge | Q_G | $V_{GS}=10\text{V}$, $V_{DS}=320\text{V}$, $I_D=5\text{A}$ (Note 1, 2) | | 18 | 24 | nC |
| Gate to Source Charge | Q_{GS} | | | 2.2 | | nC |
| Gate to Drain Charge | Q_{GD} | | | 9.7 | | nC |
| Turn-ON Delay Time | $t_{D(ON)}$ | $V_{DD}=200\text{V}$, $I_D=5\text{A}$, $R_G=25\Omega$ (Note 1, 2) | | 12 | 35 | ns |
| Rise Time | t_R | | | 46 | 100 | ns |
| Turn-OFF Delay Time | $t_{D(OFF)}$ | | | 50 | 110 | ns |
| Fall-Time | t_F | | | 48 | 105 | ns |
| SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS | | | | | | |
| Maximum Body-Diode Continuous Current | I_S | | | | 5 | A |
| Maximum Body-Diode Pulsed Current | I_{SM} | | | | 20 | A |
| Drain-Source Diode Forward Voltage | V_{SD} | $I_S=5\text{A}$, $V_{GS}=0\text{V}$ | | | 1.4 | V |
| Body Diode Reverse Recovery Time | t_{rr} | $I_S=5\text{A}$, $V_{GS}=0\text{V}$, $dI_F/dt=100\text{A}/\mu\text{s}$ | | 263 | | ns |
| Body Diode Reverse Recovery Charge | Q_{RR} | (Note 1) | | 1.9 | | μC |

Notes: 1. Pulse Test: Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$
 2. Essentially independent of operating temperature

■ TEST CIRCUITS AND WAVEFORMS

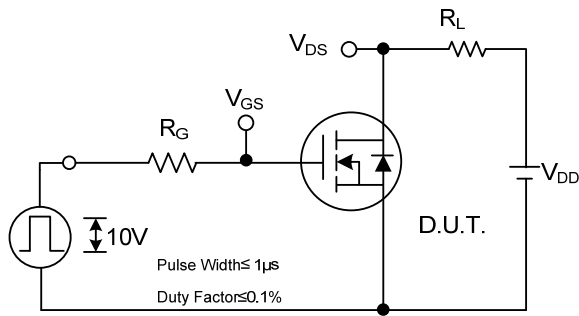


Peak Diode Recovery dv/dt Test Circuit

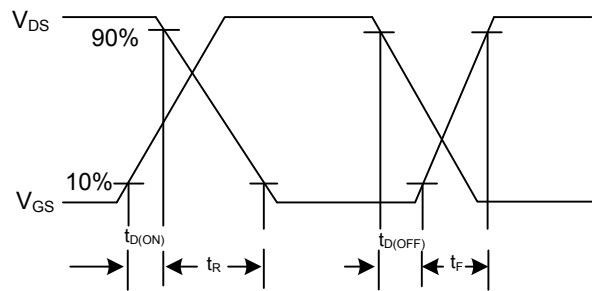


Peak Diode Recovery dv/dt Waveforms

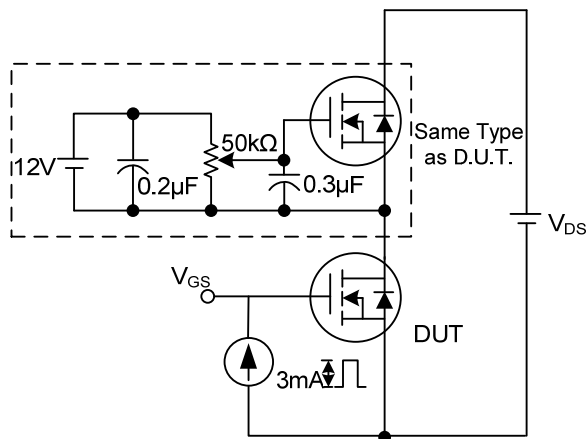
TEST CIRCUITS AND WAVEFORMS (Cont.)



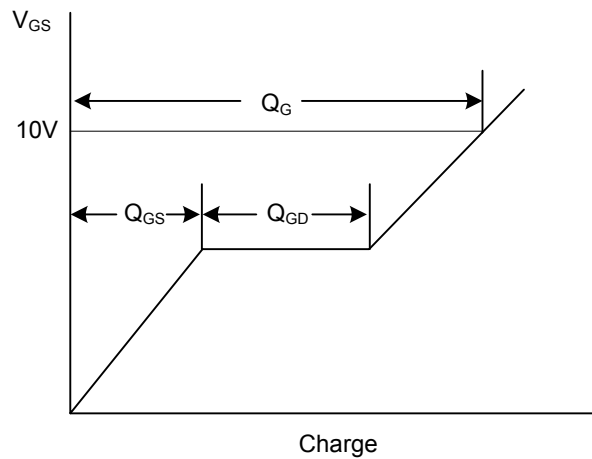
Switching Test Circuit



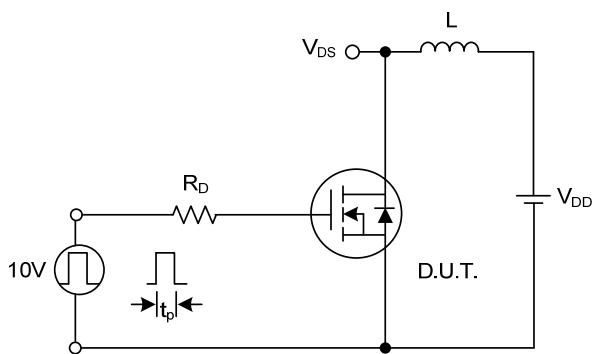
Switching Waveforms



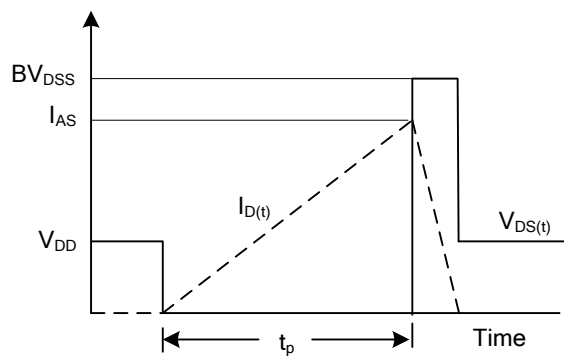
Gate Charge Test Circuit



Gate Charge Waveform



Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

TYPICAL CHARACTERISTICS

